

Description

The AOD4186 uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a

Battery protection or in other Switching application.

General Features

 $V_{DS} = 40V I_{D} = 50A$

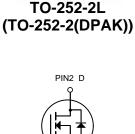
 $R_{DS(ON)}$ < 16m Ω @ V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
AOD4186	TO-252-2L(TO-252-2(DPAK))	HXY MOSFET	2500

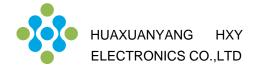
Absolute Maximum Ratings (T_c=25 ℃ unless otherwise noted)

Symbol	Parameter	Rating	Units		
V _{DS}	Drain-Source Voltage	40	V		
Vgs	Gate-Source Voltage	±20	V		
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	ontinuous Drain Current, V _{GS} @ 10V ¹ 50			
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	25	А		
Ідм	Pulsed Drain Current ²	80	А		
EAS	Single Pulse Avalanche Energy ³	19	mJ		
las	Avalanche Current	30	А		
P _D @T _C =25°C	Total Power Dissipation ⁴	20	W		
Тѕтс	Storage Temperature Range	Storage Temperature Range -55 to 150			
TJ	Operating Junction Temperature Range	erating Junction Temperature Range -55 to 150			
ReJA	Thermal Resistance Junction-ambient (Steady State) ¹	ient (Steady 55			
Rejc	Thermal Resistance Junction-Case ¹	4.32	°C/W		



Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	40	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics				•		•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	1.5	2.0	V
Duain Course On State Besistance	Б	V _{GS} =10V, I _D =8A	-	11.0	16	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =4A	-	18.9	24	mΩ
Forward Transconductance	g _{FS}	$V_{DS}=5V,I_{D}=8A$	33	-	-	S
Dynamic Characteristics			•			
Input Capacitance	C _{lss}	\/ -20\/\/ -0\/	-	964	-	PF
Output Capacitance	Coss	V_{DS} =20V, V_{GS} =0V, F=1.0MHz	-	109	-	PF
Reverse Transfer Capacitance	C _{rss}	F-1.0IVID2	-	96	-	PF
Switching Characteristics				•		•
Turn-on Delay Time	t _{d(on)}		-	5.5	-	nS
Turn-on Rise Time	t _r	V_{DD} =20V, R_L =2.5 Ω	-	14	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =3 Ω	-	24	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	\/_ 00\/ L_0A	-	22.9	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =20V, I_{D} =8A, V_{GS} =10V	-	3.5	-	nC
Gate-Drain Charge	Q_gd	v _{GS} -10v	-	5.3	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =9A	-	0.8	1.2	V



Typical Electrical and Thermal Characteristics (Curves)

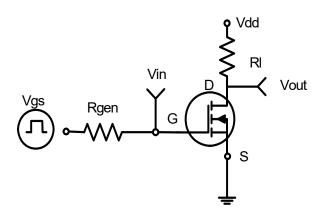


Figure 1:Switching Test Circuit

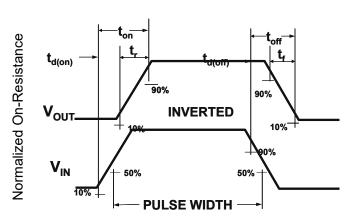


Figure 2:Switching Waveforms

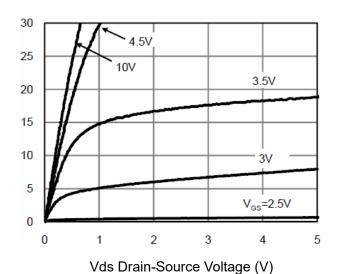


Figure 3 Output Characteristics

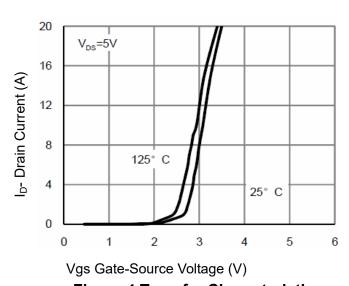


Figure 4 Transfer Characteristics

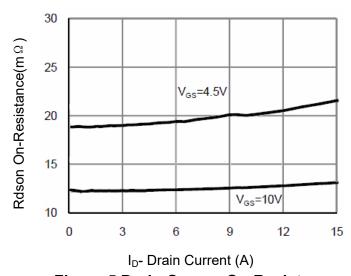


Figure 5 Drain-Source On-Resistance

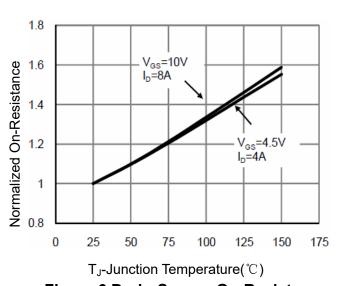
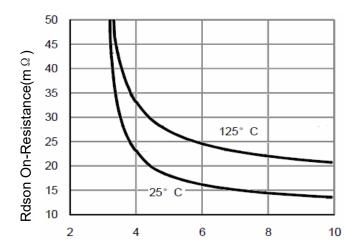


Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)

Figure 7 Rdson vs Vgs

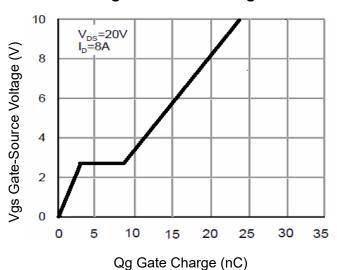


Figure 9 Gate Charge

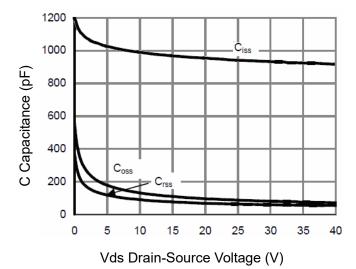
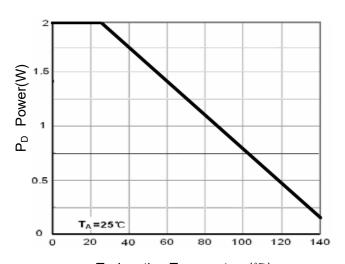


Figure 11 Capacitance vs Vds



 T_J -Junction Temperature(${}^{\circ}\mathbb{C}$)

Figure 8 Power Dissipation

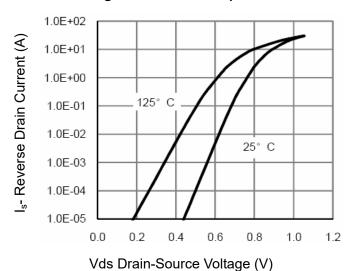
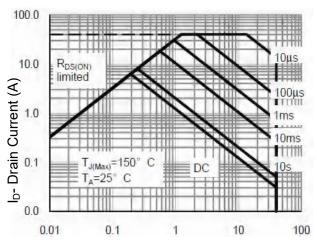


Figure 10 Source- Drain Diode Forward

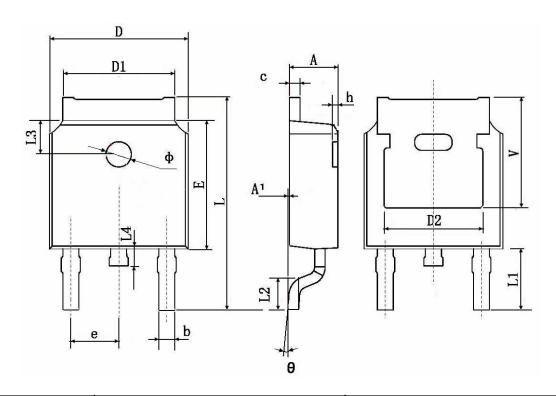


Vds Drain-Source Voltage (V)

Figure 12 Safe Operation Area



TO-252-2L(TO-252-2(DPAK)) Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



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